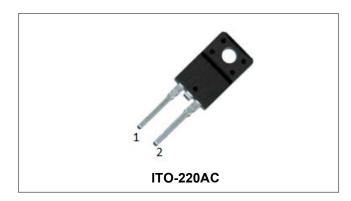






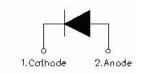
# **SDURF1560 ULTRAFAST RECTIFIER**



## **Applications**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

# **Circuit Diagram**



#### **Features**

- Ultra-Fast switching
- · High current capability
- Low reverse leakage current
- · High surge current capability
- This is a Pb Free Device
- Terminals finish: 100% Pure Tin
- . All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Maximum Ratings:**

Characteristics	Symbol	Condition Max.		Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ \end{array}$	-	600	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=105°C, rectangular wave form	15	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	160	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop *	V <sub>F1</sub>	@ 15A, Pulse, T <sub>J</sub> = 25°C	1.53	1.7	V
	$V_{F2}$	@ 15A, Pulse, T <sub>J</sub> = 125°C	1.44	1.5	V
Reverse Current *	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25°C	0.4	10	μA
	I <sub>R2</sub>	$@V_R = \text{rated } V_{R,} T_J = 125^{\circ}\text{C}$	0.3	1	mA
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>m</sub> =250mA	31	50	ns

Pulse width < 300 µs, duty cycle < 2%

- China Germany Korea Singapore United States
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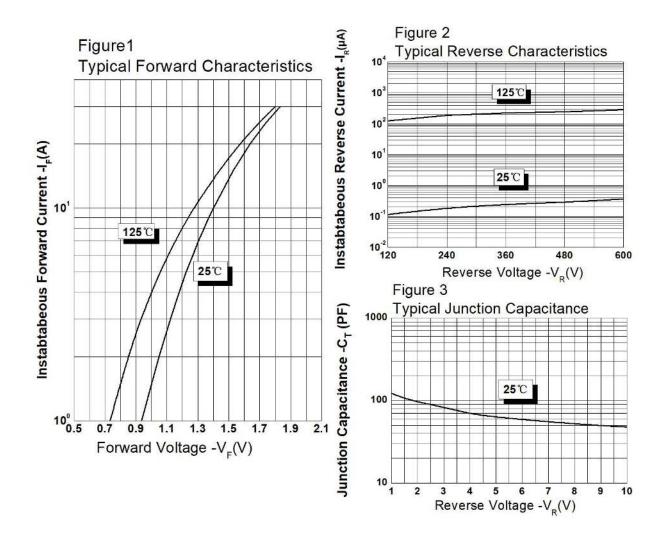




## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θJC</sub>	DC operation	1.6	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	ITO-220AC			

## **Ratings and Characteristics Curves**



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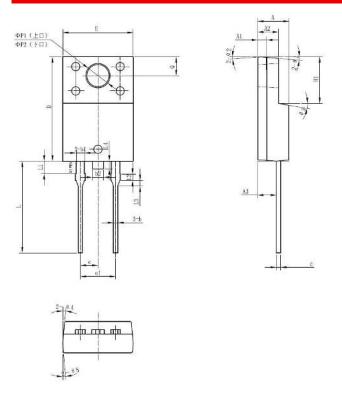
<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •





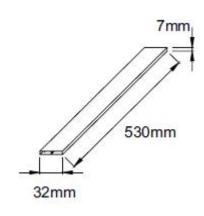


#### **Mechanical Dimensions ITO-220AC**

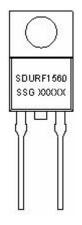


SYMBOL	Millimeters				
STIVIBUL	MIN.	TYP.	MAX.		
Α	4.30	4.50	4.70		
A1	1.10	1.30	1.50		
A2	2.80	3.00	3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
С	0.55	0.60	0.75		
D	14.80	15.00	15.20		
E	9.96	10.16	10.36		
e	-	2.55	-		
e1	_	5.10	_		
H1	6.50	6.70	6.90		
L	12.70	13.20	13.70		
<u>L1</u>	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
<u>L4</u>	-	1.10	1.50		
<b>ΦP1</b> (上口)	3.30	3.50	3.70		
<b>ΦP2</b> (下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			

## **Tube Specification**



## **Marking Diagram**



Where XXXXX is YYWWL

SDUR = Device Type F = Package type 15 = Forward Current (15A) 60 = Reverse Voltage (600V) SSG = SSG

YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

## **Ordering Information**

Device	Package	Shipping	
SDURF1560	ITO-220AC (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

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